

# EDITORIAL CALENDAR

CS China is published in Simplified Chinese and all contents are edited and translated by experienced editors and experts in the field.

Issue	Feb/Mar Issue: date: Feb 26 Materials: Feb 13 Ad booking: Feb 06 Editorial: Jan 26	Apr/May Issue: date: Apr 22 Materials: Apr 15 Ad booking: Apr 08 Editorial: Mar 25	Jun/Jul Issue: date: Jun 24 Materials: Jun 17 Ad booking: Jun 10 Editorial: May 27	Aug/Sep Issue: date: Aug 26 Materials: Aug 19 Ad booking: Aug 12 Editorial: Jul 29	Oct/Nov Issue: date: Oct 28 Materials: Oct 21 Ad booking: Oct 14 Editorial: Sep 23	Dec/Jan Issue: date: Dec 23 Materials: Dec 16 Ad booking: Dec 09 Editorial: Nov 25
Cover Story	AR/VR applications	Photonics integrated	TSSG SiC	Diamond semiconductor growing	Data center application	Smart Grid application
Tech Features	Visible light communication	Micro-LED	VCSEL laser	AI appocation	Electric vehicle application	Gallium oxide crystal growth
Column	GaN power electronics	SiC substrate	GaN substrate	Gallium oxide diode	Diamond semiconductor device	SiC IGBT
Special Supplements	SiC power electronics	AlN substrate	InP Optoelectronics	Gallium oxide MOS	Gallium oxide epitaxial	BN
Bonus Distribution	<ul style="list-style-type: none"> <li>Semicon China Shanghai, Mar 23-25</li> <li>Laser World of Photonics China, Shanghai, Mar 17-19</li> </ul>	<ul style="list-style-type: none"> <li>SNEC International PV Power Expo, May</li> </ul>	<ul style="list-style-type: none"> <li>Guangdong Int'l Lighting Fair, Jun</li> </ul>	<ul style="list-style-type: none"> <li>Semicon Taiwan, Sep</li> <li>CIOE, Shenzhen, Sep</li> <li>EDICON China, Beijing, Sep</li> </ul>	<ul style="list-style-type: none"> <li>China Solid-State Lighting, Nov</li> </ul>	

## eFocus (eNewsletter) schedule

Date	Theme
Jan 09	SiC power electronic devices
Feb 06	Diamond semiconductor growth
Mar 13	Gallium oxide crystal growth
Apr 10	Electric Vehicle Applications
May 15	GaN radio frequency device
Jun 12	Gallium oxide device
Jul 17	Photonics integrated
Aug 14	Deep UV LED
Sep 11	AlN
Oct 16	GaAs device
Nov 13	InP Optoelectronics
Dec 18	VCSEL